Form 1449 (Modified)

Atty Docket No.

Serial No.:

**Information Disclosure** 

MAT-6 Applicants: 10/723,386

Statement By Applicant

[se Several Sheets if Necessary)

Savas, et al Filing Date

November 26, 2003

Group <del>1752</del> 1743

JUN 2 4 2004

**U.S. Patent Documents** 

Example 1	No.	Patent No.	Date	Patentee	Class	Sub- class	Filing Date
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Muss	В	4,782,267	11/1/1988	Collins et al			
MOR	С	5,234,540	8/10/1993	Grant et al			
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Foreign Patent or Published Foreign Patent Application

Examiner		Document	Publication	Country or		Sub- Translation		tion
Initial	No.	No.	Date	Patent Office	Class	class	Yes	No
	I							
	J							
	K							

## Other Documents

No.	Author, Title, Date, Place (e.g. Journal) of Publication				
L	Torek et al; UV/Fluorine Etching of Native Silicon Oxides; 1992; Proceedings of the Second International Symposium on Cleaning Technology in Semiconductor Device Manufacturing; pp 80-86.				
M	Ito et al; Wafer Purification by Photochemical Dry Cleaning; March 1989, Semiconductor World; pp120-123				
N	Zhang et al; Large Area Photochemical Dry Etching of Polymide; 1993; Applied Surface Science; Vol 69; pp 299-304				
0	Vig; Ultraviolet-Ozone Cleaning of Semiconductor Surfaces; January 1992; US Army Laboratory Command (LAPCOM) Technical Report				
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Examiner: Initial citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.